

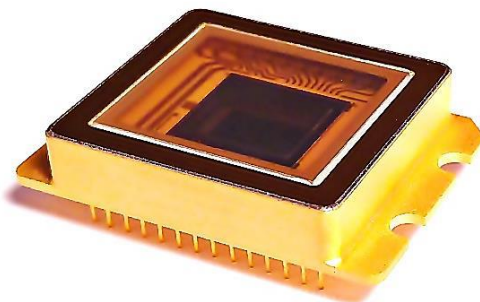


Shortwave-Infrared (1.2 - 2.2 μm) 640x512 InGaAs Focal Plane Array

FPA 640x512_P15-2.2-TE2 (BADGER-2.2-T2): with 2-Stage Thermoelectric Cooler

FEATURES	APPLICATIONS
<ul style="list-style-type: none">● 640 x 512 Array Format● 28-pin Metal SDIP Package● Embedded Thermoelectric Cooler● Built-in Temperature Sensor● 1.2 μm - 2.2 μm Spectral Range● Quantum Efficiency > 70 % at 1.9 μm● Typical Pixel Operability \geq 98 %● Snapshot ITR¹/IWR² and IMRO³ Readout Modes● 2,4 or 8 Outputs with up to 18 MHz Pixel Rate● Windowing Capability	<ul style="list-style-type: none">● Shortwave-Infrared Imaging● Hyper-/Multi-Spectral Imaging● Semiconductor Inspection / Process Monitoring● Waste Recycling● Medical Science and Biology● Ice/Slush/Moisture Mapping● High-Speed Industrial Thermal Imaging● See through Fog/Smoke● Laser Beam Profiling● Mineral Identification

¹ITR: Integrate-Then-Read - ²IWR : Integrate-While-Read - ³IMRO : Integration with Multiple ReadOut



GENERAL DESCRIPTIONS

PARAMETER	UNIT	VALUE
Sensor Technology	--	Planar InGaAs PIN
Spectral Range	μm	1.2 - 2.2
Actual Pixel Array	--	640 x 512
Effective Pixel Array	--	636 x 508
Pixel Pitch	μm	15
Image Size	mm	9.6 x 7.68
Package Type	--	28-pin Metal SDIP Package
Package Size L x W x T	mm	36.1 x 25.4 x 7.3 (without pins)
Weight	g	19.5 (\pm 0.5)



SPECIFICATIONS (ITS¹ = -40°C)

PARAMETER	UNIT	TYPICAL VALUE	COMMENTS
Dark Current ^{2,3}	fA (= 6250 e ⁻ /s)	≤ 500	Photopixel Biased @ -0.1 V Mean Value
Quantum Efficiency * Fill Factor (QEFF) ^{2,3}	%	≥ 60	λ = 1.4 μm - 2.1 μm
Response Nonuniformity ^{2,3}	%	≤ 10	At 50 % Well Occupation
Response Nonlinearity ^{2,3} (Max. Peak-to-Peak Deviation)	%	≤ 4	15 % - 85 % Well Occupation Range
Charge Capacity ^{3, 4} (Option 2 ROIC)	@ High Gain, 46.2 μV/ e ⁻	0.041	ROIC Specifications
	@ Mid Gain, 16.2 μV/ e ⁻	0.118	
	@ Low Gain, 1.39 μV/ e ⁻	1.380	
Readout Noise Floor	e ⁻	< 35	In High Gain Mode, ROIC Specifications
Noise-Equivalent Irradiance (NEI)	ph# / cm ² s	≤ 4.5 x 10 ¹⁰	In High Gain Mode, Integration Time = 3.33 ms λ = 1.9 μm
Mean Detectivity	cm√Hz / W	≥ 1.7 x 10 ¹²	
Output Swing	V	2.25	
Minimum Integration Period ³	μs	< 1	
Pixel Operability ^{2,3,5}	%	≥ 98	Percentage of Pixels with Response Output Deviation within ±30% of Mean Value
Maximum Cooling Capability ⁶ (ΔT _{MAX})	°C	≥ 60	T _{Heatsink} = 20°C

1. Readings from integrated temperature sensor (ITS).

2. These items are defined for central effective pixel array (636x508). Their values correspond to default operation conditions.

3. Contact us for further information.

4. These values are ROIC-version dependent.

5. FPA with pixel operability lower than 98% (< 98%) is categorized as a test-grade device, which, if available in stock, can be provided on request

6. Adequate heatsink and thermal interface material are the prerequisites for stable operation.

ABSOLUTE MAXIMUM RATINGS

PARAMETER	UNIT	MIN.	MAX.
Operation Temperature ⁷	°C	-40	+71
Storage Temperature ⁷	°C	-40	+80
Power Consumption ⁸	mW	---	200
TEC Bias ⁹	V	---	10
TEC Current ⁹	A	---	2.1

7. Non-condensing environment.

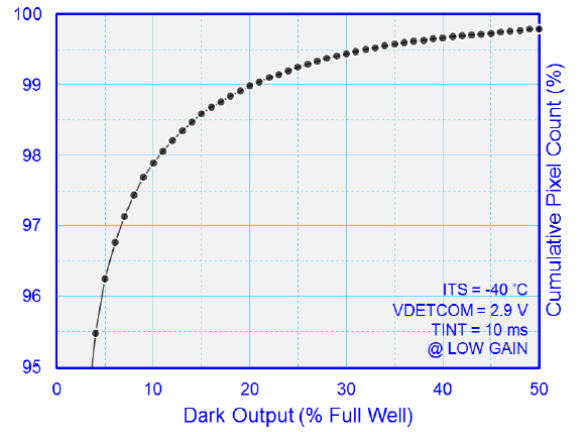
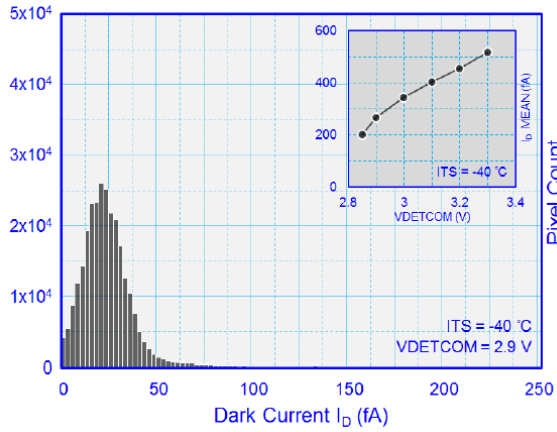
8. Without powering on the thermoelectric cooler.

9. Applied to Pin-1 for cooling operation. Operation above these maximum ratings causes excessive (local) heat accumulation and may result in permanent damage to the cooler.

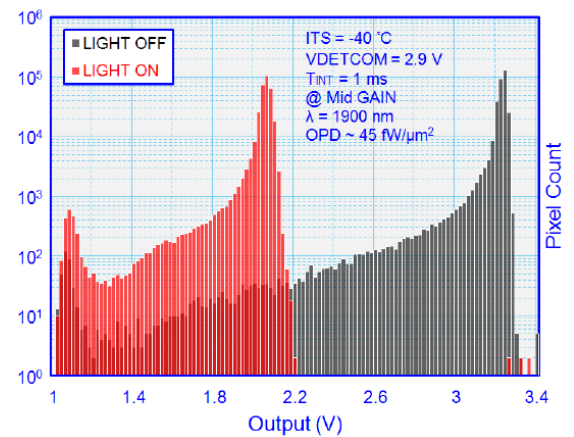
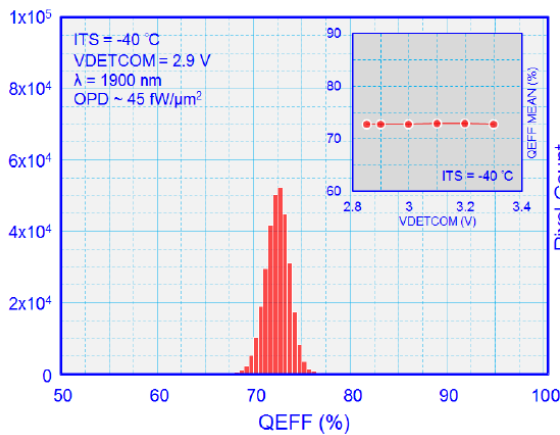


EXAMPLE CURVES

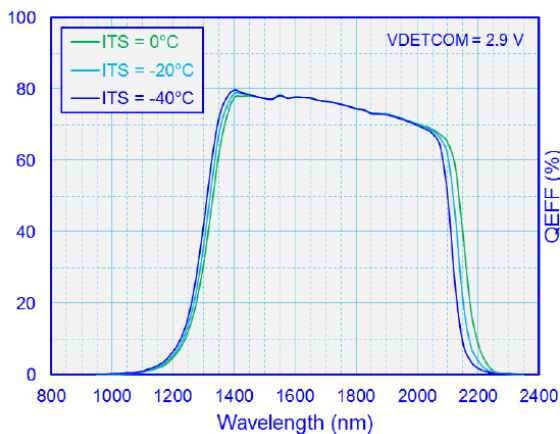
Histograms of Dark Condition



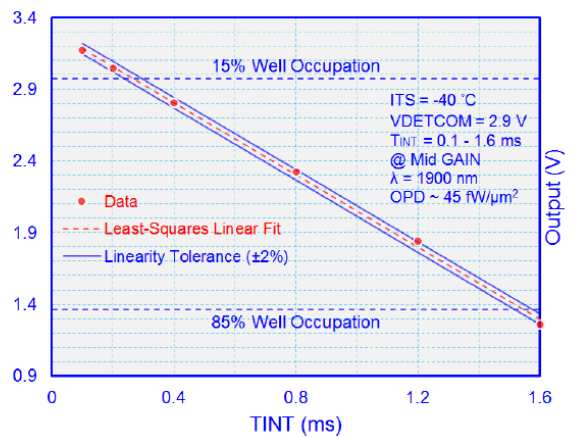
Histograms of Illuminated Condition



QEFF Spectrum



Output Linearity



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